TOSHIBA Transistor Silicon-Germanium NPN Epitaxial Planar Type

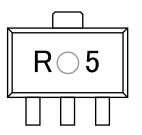
MT3S111P

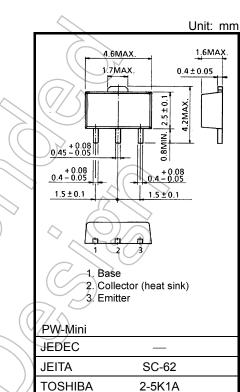
VHF-UHF Low-Noise, Low-Distortion Amplifier Applications

Features

- Low-Noise Figure: NF=0.95 dB (typ.) (@f=1 GHz)
- High Gain: $|S_{21e}|^2$ =10.5 dB (typ.) (@f=1 GHz)

Marking





Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-emitter voltage	VCES	13	$\langle \chi \rangle$
Collector-emitter voltage	VCEO	6	×
Emitter-base voltage	VEBO	0.6	~
Collector-current	IC (100) mA
Base-current	IB	10	mA
Collector power dissipation	Pc	300	mW
Collector power dissipation	P _C (Note 1)		W
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55 to 150	°C

Weight:0.05 g (typ.)

Note 1: The device is mounted on a ceramic board (16 mm × 16 mm × 0.8 mm (t))

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Microwave Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Transition frequency	f _T	V _{CE} =5 V, I _C =30 mA	6	8	_	GHz
Insertion gain	S _{21e} ² (1)	V _{CE} =5 V, I _C =30 mA, f=500 MHz	_	16	_	dB
	S _{21e} ² (2)	V _{CE} =5 V, I _C =30 mA, f=1 GHz	8.5	10.5	_	dB
Noise figure	NF(1)	V _{CE} =5 V, I _C =30 mA, f=500 MHz	Ĥ	0.7	_	dB
	NF(2)	V _{CE} =5 V, I _C =30 mA, f=1 GHz	Ą	0.95	1.25	dB
3 rd order intermodulation distortion output intercept point	OIP3	V _{CE} =5 V, I _C =30 mA, f=500 MHz, ⊿f=1 MHz	Z)	32		dBmW

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min Typ.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} =5 V, I _E =0 A	- 67	0.1	μA
DC current gain	h _{FE}	V _{CE} =5 V, I _C =30 mA	200 +	400	—
Output capacitance	C _{ob}	V _{CB} =5 V, I _E =0 A, f=1 MHz	- 1.6	/_	pF
Reverse transfer capacitance	C _{re}	V _{CB} =5 V, I _E =0 A, f=1 MHz (Note 2)		1.3	pF

Note 2: C_{re} is measured using a 3-terminal method with capacitance bridge.

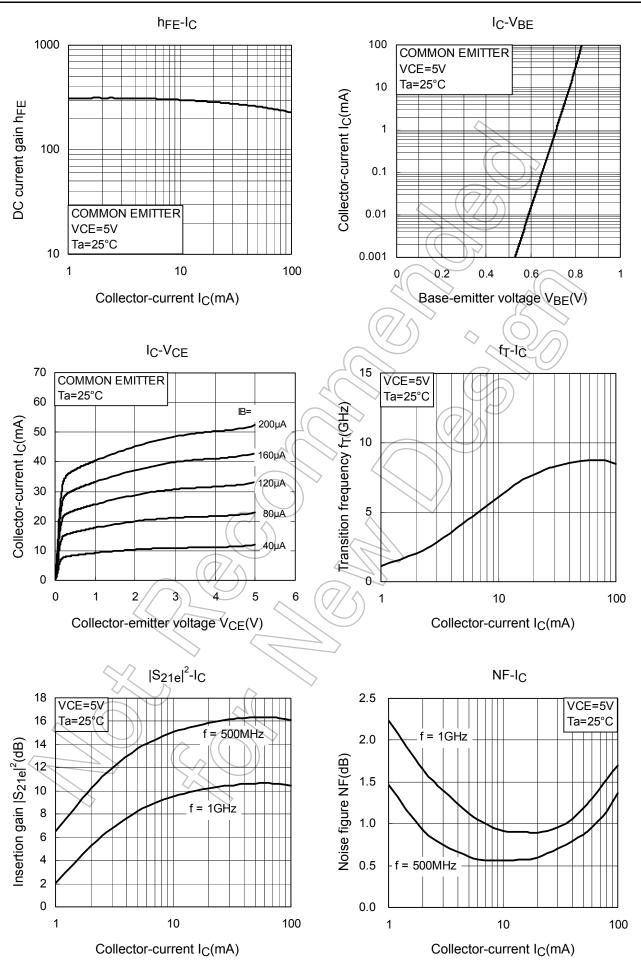
Caution:

This device is sensitive to electrostatic discharge due to the high frequency transistor process of

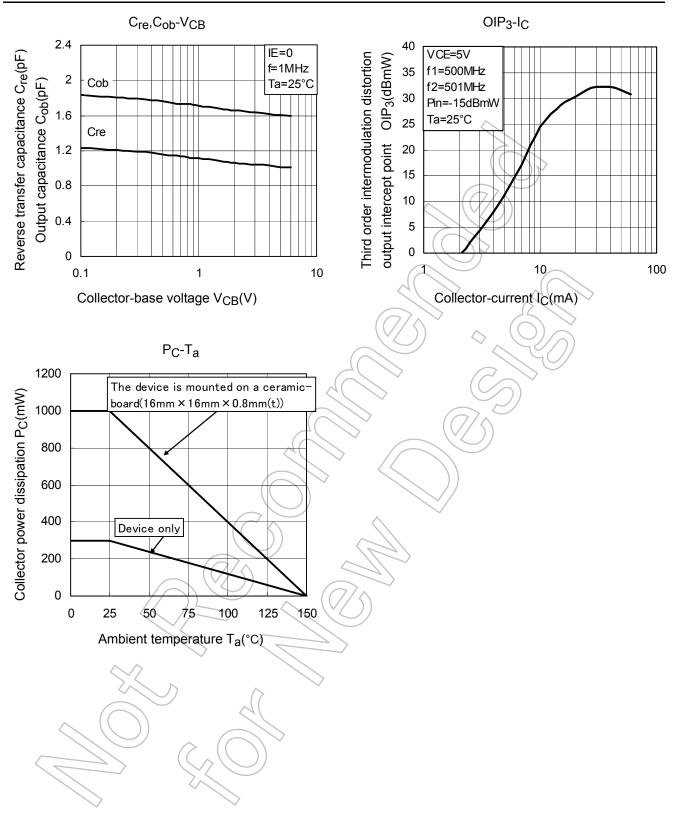
f_T=60 GHz class which is used for this product.

Please make tool and equipment earthed enough when you handle.

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